

Afisarea articolelor 1-3(3) pentru cuvântul-cheie "Electric space charge"

New propylamine sensor using artificial dimorphite

Țiuleanu Dumitru, Marian Svetlana, Guba M., Potje-Kamloth Karin, Liess Hans Dieter

Technical University of Moldova

Proceedings of the International Semiconductor Conference

Vol. 1. 1998. New Jersey. [DOI 10.1109/SMICND.1998.732248](https://doi.org/10.1109/SMICND.1998.732248).

Disponibil online 6 December, 2023. Descarcări-0. Vizualizări-170

Formation of a double electric layer at the $ZnIn_2Sm_{+3}$ ($m = 1,2,3$) - $H_2O(S_2-/S_{22-})$ interface

Țiuleanu Ion, Simășchevici Alexei, Sprincean Ala

Institute of Applied Physics, Academy of Sciences of Moldova

Proceedings of the International Semiconductor Conference

Vol. 2. 2001. New Jersey. .

Disponibil online 29 November, 2023. Descarcări-0. Vizualizări-137

Porous III-V compound semiconductors: Formation, properties, and comparison to silicon

Foll Helmut¹, Carstensen Juergen¹, Langa Sergiu^{1,2}, Christophersen Marc¹, Tighineanu Ion²

² Technical University of Moldova

Physica Status Solidi (A) Applied Research

/ 2003 / ISSN 0031-8965 /ISSNe 1521-396X

Disponibil online 20 November, 2023. Descarcări-0. Vizualizări-86



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Institutul de Dezvoltare a Societății Informaționale.

Actualizat: 25.06.2024, accesat: 25.06.2024

Disponibil: <https://ibn.idsi.md>

